

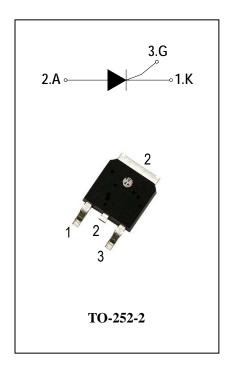
## **SCRs**

## **General Description**

Available either in sensitive or standard gate triggering levels, the 12A SCR series is suitable to fit all modes of control found inapplications such as overvoltage crowbar protection, motor control circuits in power tools and kitchen aids, in-rush current limiting circuits, capacitive discharge ignition, voltage regulation circuits...

#### **Features**

- ◆ Repetitive Peak Off-State Voltage: 600V and 800V
- ◆ R.M.S On-State Current (IT(RMS)= 12 A)
- ♦ These are Pb-Free Devices



## **Absolute Maximum Ratings**

Symbol	Items	Conditions		Ratings	Unit				
$V_{DRM}$	Repetitive Peak Off-State Voltage	Ti-25°C	ADS12A60E		V				
$V_{RRM}$	Repetitive peak reverse voltage	Tj=25°C	ADS12A80E	800	V				
I <sub>T(AV)</sub>	Average On-State Current	Half Sine Wave , Tc = 105°C		8	Α				
I <sub>T(RMS)</sub>	R.M.S On-State Current	Half Sine Wave , Tc = 105°C		12	Α				
I <sub>TSM</sub>	Surge On-State Current	1/2 Cycle, Sine Wave Non-Repetitive, tp=10ms(50Hz)Tj =25°C		140	А				
I <sup>2</sup> t	I <sup>2</sup> t for Fusing	Tj =25°C,tp =10ms		98	A <sup>2</sup> S				
P <sub>GM</sub>	Forward Peak Gate Power Dissipation	Tj =125°C, Pulse Width ≤ 20μs		5	W				
$P_{G(AV)}$	Forward Average Gate Power Dissipation	Tj =25°C, tp =10ms		1	W				
I <sub>GM</sub>	Peak Gate Current	Tj =125°C, Pulse Width ≤ 20μs		4	Α				
Tj	Operating Junction Temperature			-		- 40 ~ 125	°C		
T <sub>STG</sub>	Storage Temperature							- 40 ~ 150	°C





# ADS12A60E/80E

## **Electrical Characteristics** (Tj = 25°C unless otherwise specified)

Symbol	Items	Conditions		ADS12A60E/80E		Unit		
				Т	S	Blank		
		$V_{DRM} = V_{RRM}, R_{GK} = 1K\Omega$			5		uA	
I <sub>DRM</sub>	Peak Forward Reverse	Tj = 25°C	Max	D .			u, t	
I <sub>RRM</sub>	Blocking Current	$V_{DRM} = V_{RRM}, R_{GK} = 1K\Omega$	Max.	2		mA		
		Tj = 125°C		2				
V <sub>TM</sub>	Peak On-State Voltage	I <sub>TM</sub> = 24A, t <sub>p</sub> = 380 μs	Max.	1.55		V		
	Non Trigger Cate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$	Min.	0.0		V		
$V_{GD}$	Non-Trigger Gate Voltage	$R_{GK} = 1K\Omega$ $Tj = 125$ °C	IVIII1.	0.2				
$V_{GT}$	Gate Trigger Voltage	V 40V B 000	Max.	1.5		V		
I <sub>GT</sub>	Gate Trigger Current	$V_D = 12V$ , $R_L = 33\Omega$	Max.	0.2	15	30	mA	
I <sub>H</sub>	Holding Current	$I_T = 0.5A$ $R_{GK} = 1K\Omega$	Max.	5	30	40	mA	
ΙL	Latching Current	$I_G = 1.2 I_{GT} R_{GK} = 1 K\Omega$	Max.	7	50	60	mA	
dV/dt	Critical Rate of Rise of	$V_D = 2/3V_{DRM}$ gate open		000	500	000	\ //	
	Off-State Voltage	$R_{GK}$ = 1K $\Omega$ Tj = 125°C	Min.	200	500	600	V/µs	
R <sub>th(j-c)</sub>	Junction to case (AC)		Max.	1.8		°C/W		
R <sub>th(j-a)</sub>	Junction to ambient(Copper surface under tab:S=0.5cm <sup>2</sup> )		Max.	70			°C/W	

10

current

on-state

140

FIG.2: Average on-state current VS Allowable

case Temperature(Single phase half wave)

Tj=25°C Max

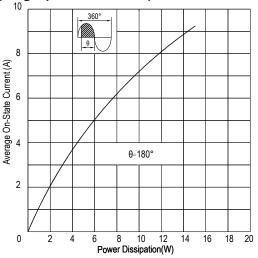
80

Surge On-State Current(A)

20

120

FIG.1: Maximum average power dissipation (Single phase half wave)



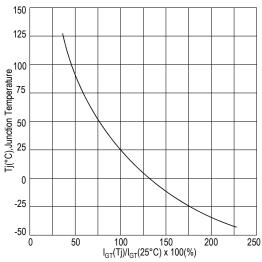
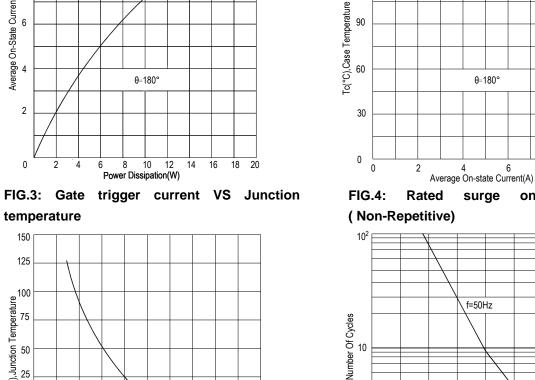
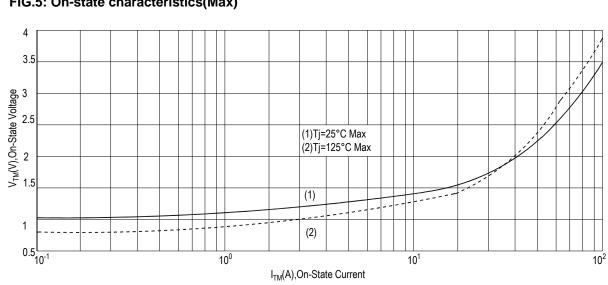


FIG.5: On-state characteristics(Max)







## ADS12A60E/80E

FIG.6:Holding current and Latching current VS Junction temperature

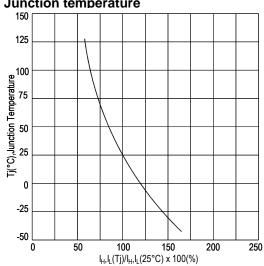


FIG.8: Gate trigger current VS Junction temperature for type T gate triggering

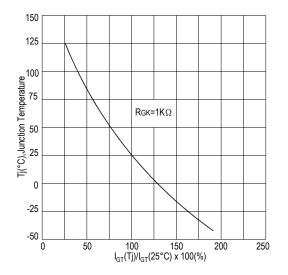


FIG.7: Gate trigger voltage VS Junction

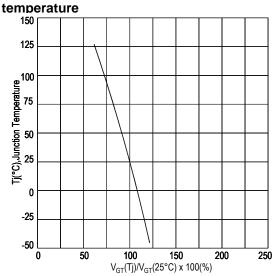
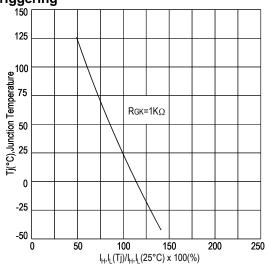


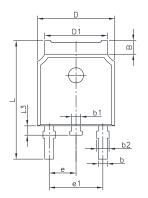
FIG.8:Holding current and Latching current VS Junction temperature for type T gate triggering

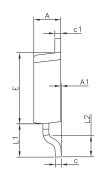


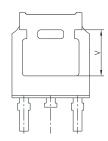


#### **PACKAGE MECHANICAL DATA**

#### **TO-252-2 Package Dimension**

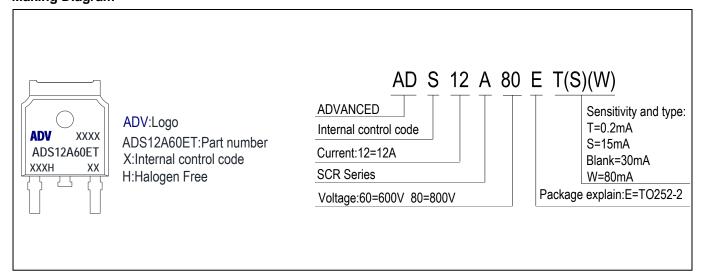






Cumala	Dimensions		Dimensions		
Symb	In Millimeters		In Inches		
ol	Min.	Max.	Min.	Max.	
Α	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
В	1.070	1.220	0.042	0.048	
b	0.720	0.850	0.028	0.033	
b1	0.720	0.850	0.028	0.033	
С	0.450	0.620	0.017	0.024	
c1	0.450	0.620	0.017	0.024	
D	6.350	6.650	0.250	0.262	
D1	5.200	5.400	0.205	0.213	
Е	5.900	6.200	0.232	0.244	
е	2.300 TYP.		0.091 TYP.		
e1	4.500	4.700	0.177	0.185	
L	9.500	10.60	0.374	0.396	
L1	2.550	2.900	0.100	0.114	
L2	1.400	1.780	0.055	0.070	
L3	0.600	0.900	0.024	0.035	
V	3.950 REF.		0.155 REF.		

## **Making Diagram**



## **Ordering information**

Part number	Package	Marking	Packing	Quantity		
ADC12A60E#	TO-252-2	ADS12A60E#	Tube	80pcs		
ADS12A60E#			Embossed tape	2500pcs		
AD040A00E#	TO-252-2	ADS12A80E#	Tube	80pcs		
ADS12A80E#			Embossed tape	2500pcs		
Note:# = Gate Trigger Current Sensitivity and type						



## ADS12A60E/80E

#### Notice

- 1. All information included in this document such as product data, diagrams, charts, programs, algorithms, and application circuit examples, is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any ADV products listed in this document, please confirm the latest product information with a ADV sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by ADV such as that disclosed through our website. (http://www.advsemi.com)
- 2 . ADV has used reasonable care in compiling the information included in this document, but ADV assumes no liability whatsoever for any damages incurred as a result of errors or omissions in the information included in this document.
- 3. You should use the products described herein within the range specified by ADV, especially with respectvto the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. ADV shall have no liability for malfunctions or damages arising out of the use of ADV products beyond such specified ranges.
- 4. When using or otherwise relying on the information in this document, you should evaluate the information in light of the total system before deciding about the applicability of such information to the intended application. ADV makes no representations, warranties or guaranties regarding the suitability of its products for any particular application and specifically disclaims any liability arising out of the application and use of the information in this document or ADV products.
- 5 . Although ADV endeavors to improve the quality and reliability of its products, IC products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Please be sure to implement safety measures to guard against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a ADV product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other applicable measures. Among others, since the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by you.
- 6. This document is provided for reference purposes only so that ADV customers may select the appropriate ADV products for their use. ADV neither makes warranties or representations with respect to the accuracy or completeness of the information contained in this document nor grants any license to any intellectual property rights or any other rights of ADV or any third party with respect to the information in this document.
- 7 . ADV shall have no liability for damages or infringement of any intellectual property or other rights arising out of the use of any information in this document, including, but not limited to, product data, diagrams, charts, programs, algorithms, and application circuit examples.
- 8. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written approval from ADV.

6 / 6 www.advsemi.com Feb,2017 -Rev.3.05